

SML40EUZ06B

Back of Case. Cathode SML 40EUZ06B Anode

See Package outline for mechanical data and more details

TO247 Package

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Key Parameters

V_R	(max)	600V		
V_{F}	(typ)	2.15V		
I_{F}	(max)	40A		
t _{rr}	(max)	40nS		

Enhanced Ultrafast Recovery Diode 600 Volt, 40 Amp

TECHNOLOGY

The planar passivated and enhanced ultrafast recovery diode features a triple charge control action utilising Semelab's graded Buffer Zone technology combined with low emitter efficiency and local lifetime control techniques.

BENEFITS

- Very fast recovery for low switching losses
- · Ultra soft recovery with low EMI generation
- · High dynamic ruggedness under all conditions
- Low temperature dependency
- Low on-state losses with positive temperature coefficient
- Stable blocking voltage and low leakage current
- · Avalanche rated for high reliability circuit operation

APPLICATIONS

- Freewheeling Diode for IGBTs and MOSFETs
- Uninterruptible Power Supplies UPS
- Switch Mode Power Supplies SMPS
- Inverse and Clamping Diode
- Snubber Diode
- Fast Switching Rectification

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C unless otherwise stated)

V _{RRM}	Peak Repetitive Reverse Voltage	600V		
V_R	DC Reverse Blocking Voltage	600V		
I _{FAV}	Average Forward Current @T _C = 85°C	40A		
I _{FSM(surge)}	Repetitive Forward Current	100A		
I _{FS(surge)}	Non-Repetitive Forward Current(10msec pulse)	400A		
P_{D}	Power Dissipation @T _C = 85°C	90W		
W_{AVL}	Avalanche Energy(L=40mH)	30mJ		
T_J , T_STG	Operating & Storage Junction Temperature	- 55 to 150°C		

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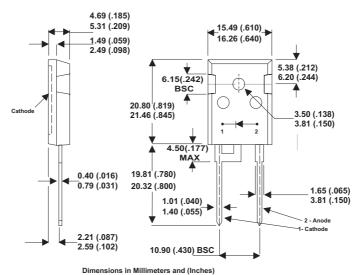


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ELECTRICAL CHARACTERISTICS ($T_{Case} = 25^{\circ}C$ unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
STATIC	ELECTRICAL CHARACTERISTI	С					
		I _F = 40A	T _j = 25°C		2.15	2.5	
V _F Forward Voltage	Forward Voltage Drop	I _F = 40A	T _j = 125°C		2.2		V
		I _F = 20A	$T_j = 25^{\circ}C$		1.75		
I _R Leakage	Lackaga Current	V _R = 600V	$T_j = 25^{\circ}C$		0.8	300	μΑ
	Leakage Current	V _R = 600V	T _j = 125°C		0.6	3	mA
C _T	Junction Capacitance	V _R = 200V	T _j = 25°C		45		pF
DYNAMI	C ELECTRICAL CHARACTERIS	STIC	•				l
Q _{rr}	Reverse Recovery Charge	$V_R = 300V$ $d_i / d_t = 800A/\mu s$	-		0.5		μС
I _{rr}	Reverse Recovery Current				22		А
t _{rr}	Reverse Recovery Time		1 _J = 25 C		50		nsec
Q _{rr}	Reverse Recovery Charge	$V_R = 300 \text{ V}$ $d_i / d_t = 800 \text{A/}\mu\text{s}$	· ·		0.8		μС
I _{rr}	Reverse Recovery Current				30		А
t _{rr}	Reverse Recovery Time				54		nsec
t _{rr}	Reverse Recovery Time	V _R = 50V	I _F = 1A		40		nsec
		$d_{i} / d_{t} = 100A/\mu s$	$T_J = 25^{\circ}C$				
THERM	AL AND MECHANICAL CHARA	CTERISTICS		<u>'</u>	'		•
$R_{\theta jc}$	Junction to Case Thermal Resistance					0.93	°C/W
TL	Lead Temperature					300	°C
LS	Stray Inductance				10		nH
Torque	Mounting Torque					1.1	N.m

TO-247 clip Package



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